
High-Performance IR Emitter and IR PIN Photodiode in Subminiature SMT Package

Technical Data

HSDL-44XX IR Emitter Series HSDL-54XX IR Detector Series

Features

- **Subminiature Flat Top and Dome Package**
Size – 2x2 mm
- **IR Emitter**
875 nm TS AlGaAs
Intensity – 17 mW/sr
Speed – 40 ns
- **Wide Range of Drive Currents**
500 μ A to 500 mA
- **IR Detector**
PIN Photodiode
High Sensitivity
Speed – 7.5 ns
- **Flexible Lead Configurations**
Surface Mount or
Through Hole

Applications

- **Short Distance IR Links**
- **IrDA Compatible**
- **Small Handheld Devices**
Pagers
Industrial Handhelds
- **Diffuse LANs**
- **Wireless Audio**

Description

Flat Top Package

The HSDL-4400 Series of flat top IR emitters use an untinted, nondiffused, truncated lens to provide a wide radiation pattern that is useful for short distance communication where alignment of the emitter and detector is not critical. The HSDL-5400 Series of flat top IR detectors uses the same truncated lens design as the HSDL-4400 Series of IR emitters with the added feature of a black tint that acts as an optical filter to reduce the effects of ambient light, such as sun, incandescent and fluorescent light from interfering with the IR signal.

Dome Package

The HSDL-4420 Series of dome IR emitters uses an untinted, nondiffused lens to provide a 24 degree viewing angle with high on-axis intensity. The HSDL-5420 Series of IR detectors uses the same lens design as the HSDL-4420 IR emitter and optical filter used in the HSDL-5400 IR detector.



Lead Configuration

All of these devices are made by encapsulating LED and PIN photodiode chips on axial lead frames to form molded epoxy subminiature packages. A variety of lead configurations is available and includes: surface mount gull wing, yoke lead, or Z-bend and through hole lead bends at 2.54 mm (0.100 inch) center spacing.

Technology

The subminiature solid state emitters utilize a highly optimized LED material, transparent substrate aluminum gallium arsenide, TS AlGaAs. This material has a very high radiant efficiency, capable of producing high light output over a wide range of drive currents and temperature.

Device Selection Guide

IR Emitters

Part Number	Device Description ^[1]	Device Outline Drawing
HSDL-4400	LED, Flat Top, 110 deg	A
HSDL-4420	LED, Dome, 24 deg	B

IR Detectors

Part Number	Device Description ^[1]	Device Outline Drawing
HSDL-5400	PIN Photodiode, Flat Top, 110 deg	C
HSDL-5420	PIN Photodiode, Dome, 28 deg	D

Package Configuration Options

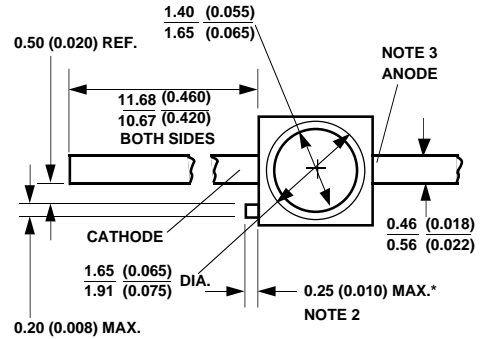
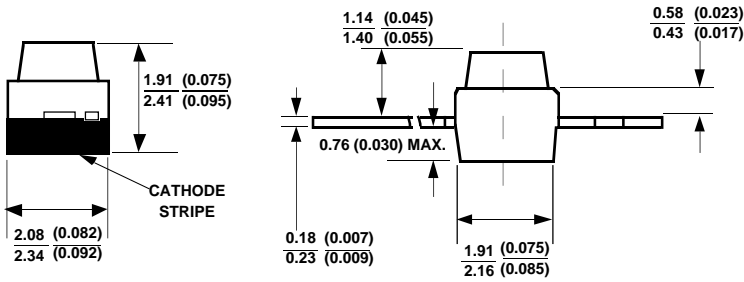
Option Code	Package Configuration Description		Package Outline Drawing
011	Gull Wing Lead, Tape and Reel ^[2]		E, J, M
021	Yoke Lead, Tape and Reel ^[2]	Surface Mount Lead	F, K, M
031	Z-Bend, Tape and Reel ^[2]		G, L, M
1L1	2.54 mm (0.100 in) Center Lead Spacing	Long Leads; 10.4 mm (0.410 in)	Thru Hole Lead
1S1		Short Leads; 3.7 mm (0.145 in)	
No Option	Straight Leads ^[3]		Prototyping

Notes:

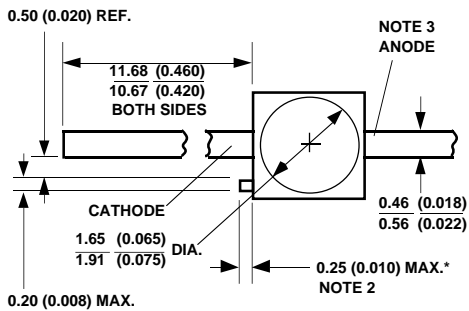
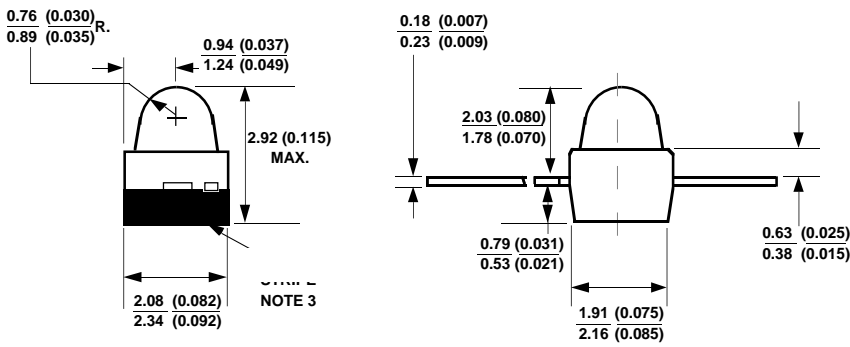
1. IR Emitters have untinted, nondiffused lenses and IR Detectors have black tinted, nondiffused lenses.
2. Emitters and detectors are supplied in 12 mm embossed tape on 178 mm (7 inch) diameter reels, with 1500 units per reel. Minimum order quantity and order increment are in quantity of reels only.
3. Emitters and detectors are supplied in bulk form in bags of 50 units.

Package Dimensions

(A) Flat Top Emitters



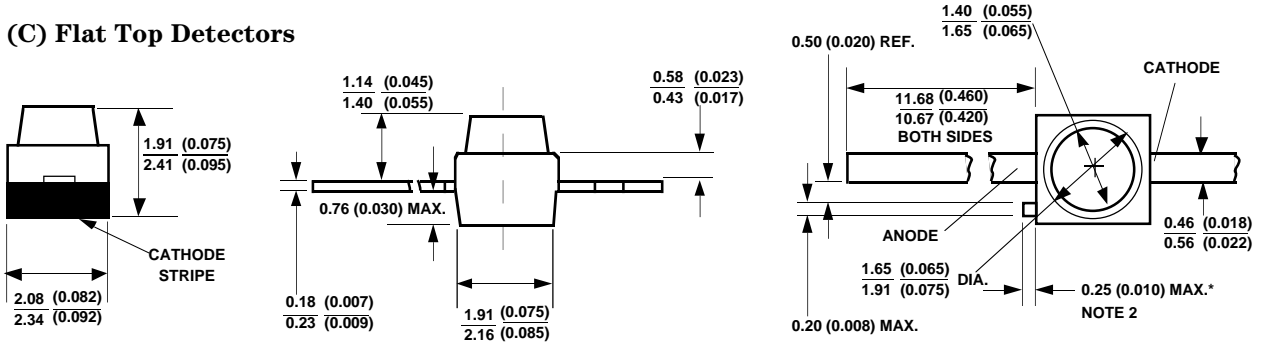
(B) Dome Emitters



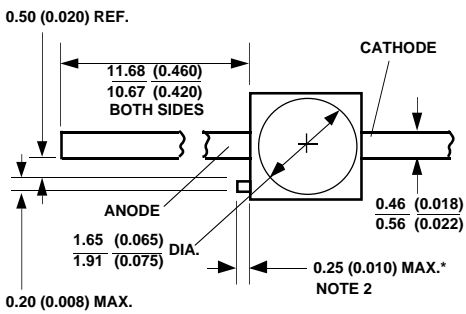
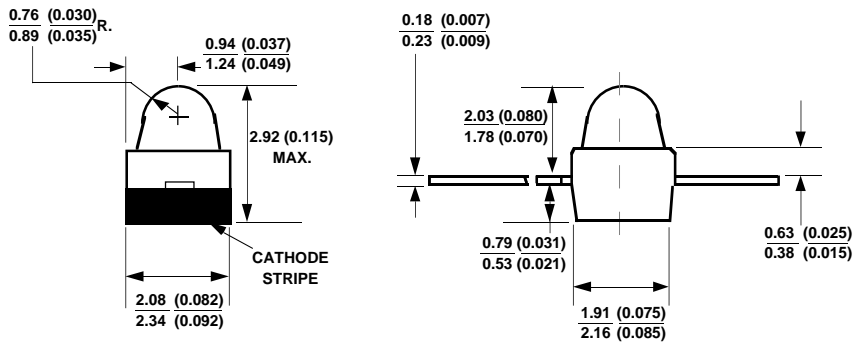
NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETRES (INCHES).
2. PROTRUDING SUPPORT TAB IS CONNECTED TO ANODE LEAD.
3. LEAD POLARITY FOR THESE TS AlGaAs SUBMINIATURE LAMPS IS OPPOSITE TO THE LEAD POLARITY OF SUBMINIATURE LAMPS USING OTHER LED TECHNOLOGIES. CATHODE STRIPE MARKING IS BLACK.

(C) Flat Top Detectors



(D) Dome Detectors



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS (INCHES).
2. PROTRUDING SUPPORT TAB IS CONNECTED TO CATHODE LEAD.
3. CATHODE STRIPE MARKING IS SILVER.

Package Dimensions

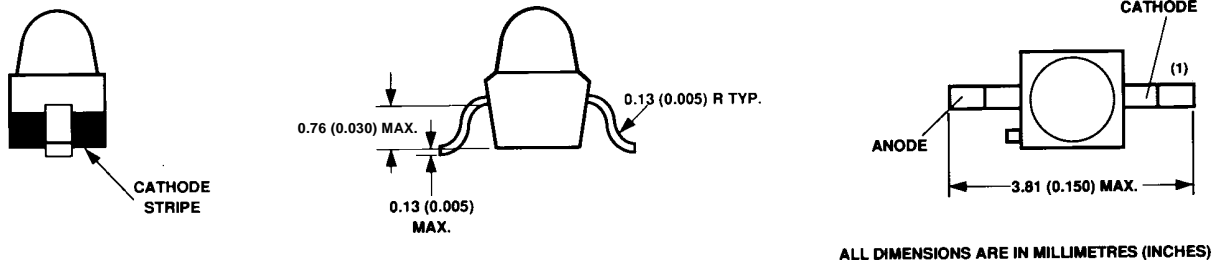
The following notes affect the package outline drawings E through I.

1. The pinout represents the HSDL-54XX IR detectors where the protruding support tab is closest to the anode lead. While the pinout is reversed for the HSDL-44XX

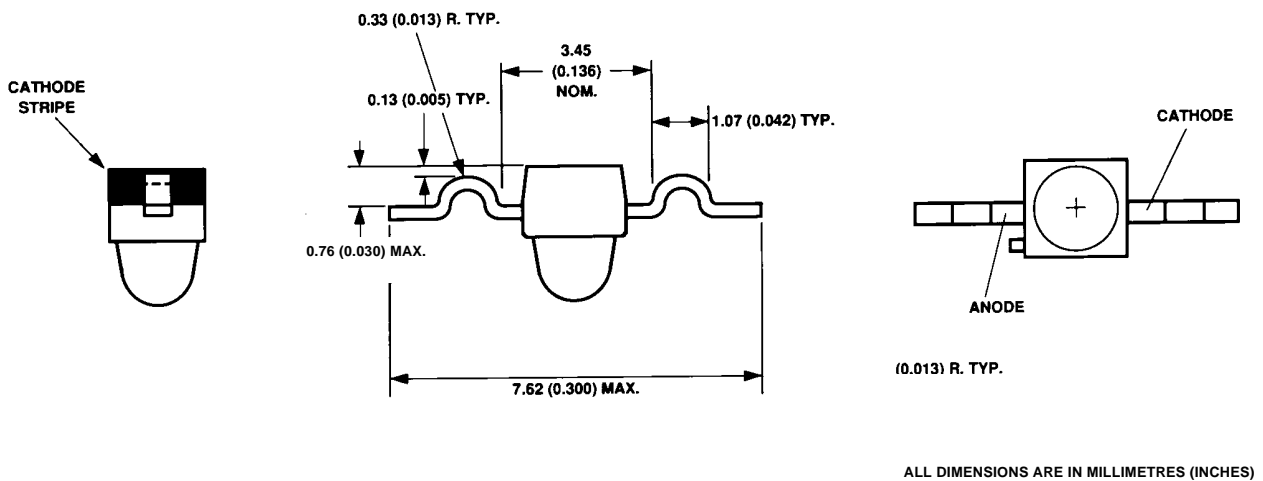
IR emitters where the protruding support tab is closest to the cathode lead.

2. The protruding support tab of the HSDL-54XX is connected to the cathode lead. While the protruding support tab of the HSDL-44XX is connected to the anode lead.

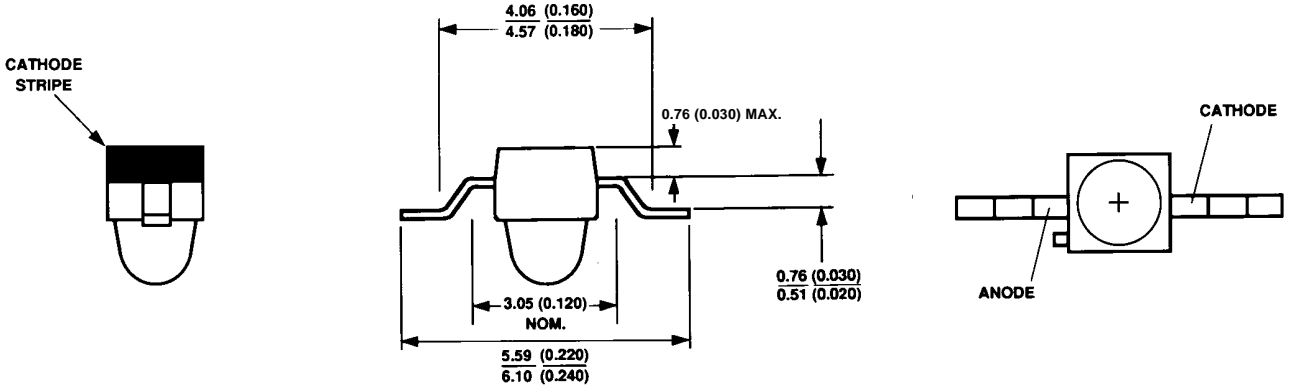
(E) Gull Wing Lead, Option 011



(F) "Yoke" Lead, Options 021

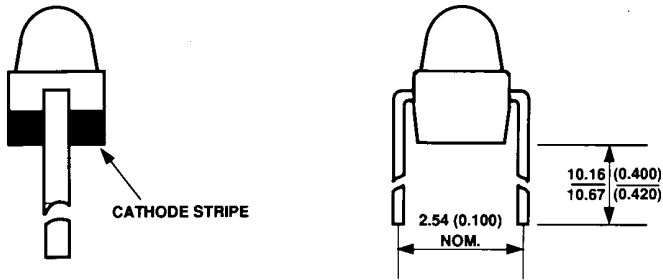


(G) Z-Bend Lead, Options 031



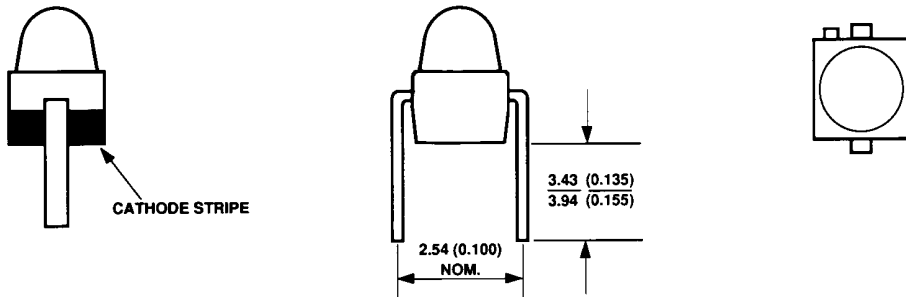
ALL DIMENSIONS ARE IN MILLIMETRES (INCHES)

(H) Thru Hole Lead Option 1L1



ALL DIMENSIONS ARE IN MILLIMETRES (INCHES)

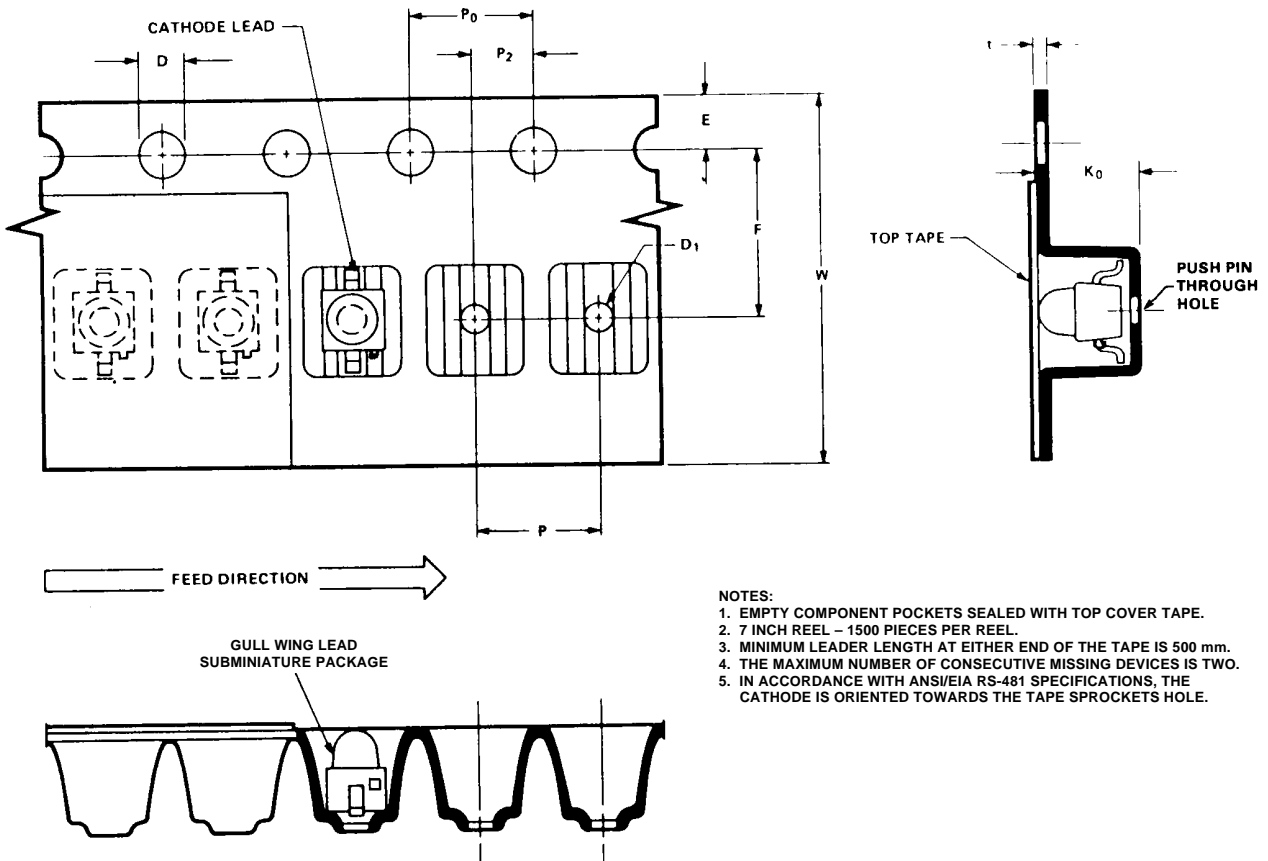
(I) Thru Hole Lead Option 1S1



ALL DIMENSIONS ARE IN MILLIMETRES (INCHES)

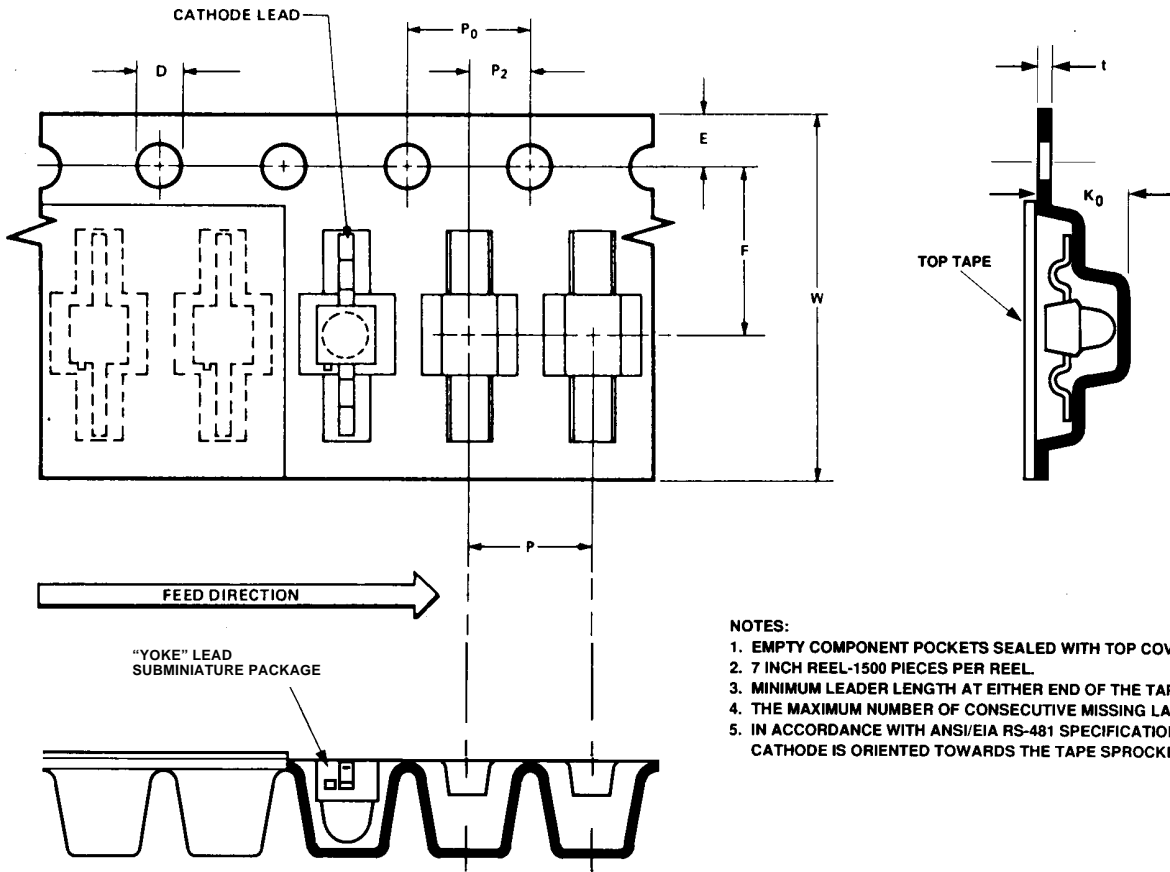
Package Dimensions: Surface Mount Tape and Reel Options

(J) 12 mm Tape and Reel, Gull Wing Lead, Option 011



At the time of this publication XX/96, Light Emitting Diodes (LEDs) that are contained in this product are regulated for eye safety in Europe by the Commission for European Electrotechnical Standardization (CENELEC) EN60825-1. Please refer to Application Brief I-008 for more information.

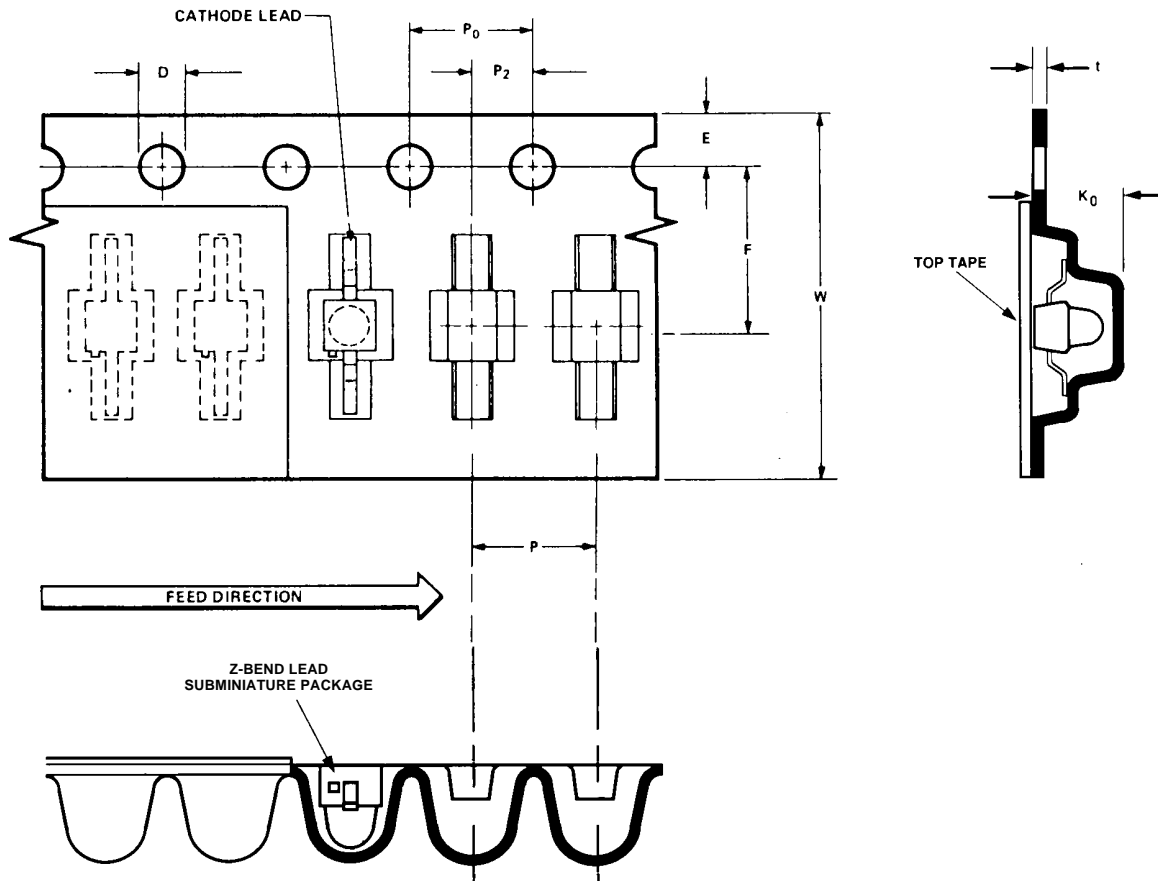
(K) 12 mm Tape and Reel, "Yoke" Lead, Option 021



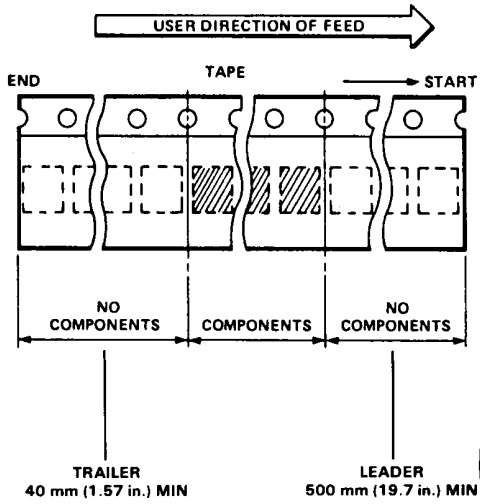
NOTES:

1. EMPTY COMPONENT POCKETS SEALED WITH TOP COVER TAPE.
2. 7 INCH REEL-1500 PIECES PER REEL.
3. MINIMUM LEADER LENGTH AT EITHER END OF THE TAPE IS 500 mm.
4. THE MAXIMUM NUMBER OF CONSECUTIVE MISSING LAMPS IS TWO.
5. IN ACCORDANCE WITH ANSI/EIA RS-481 SPECIFICATIONS, THE CATHODE IS ORIENTED TOWARDS THE TAPE SPROCKET HOLE.

(L) 12 mm Tape and Reel, Z-Bend Lead, Option 031



(M) 12 mm Tape and Reel

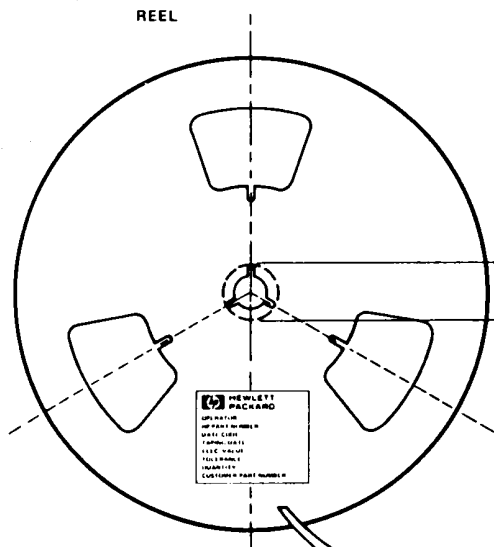


TOLERANCES (UNLESS OTHERWISE SPECIFIED):
 .X ± .1; .XX ± .05 (.XXX ± .004)

DIMENSIONS PER ANSI/EIA STANDARD RS-481. ALL DIMENSIONS ARE IN MILLIMETRES (INCHES).

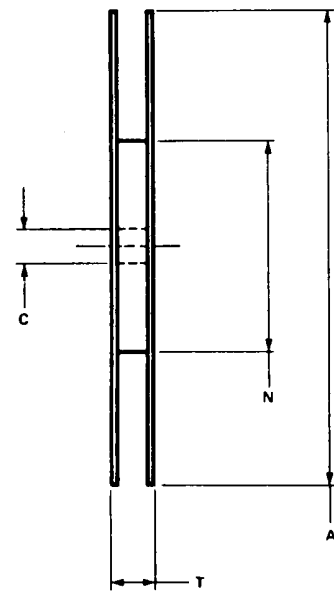
A	178.0 ± 2.0 (7.0 ± 0.08) DIA.
C	13.0 (0.512) DIA. TYP.
D	1.55 (0.061 ± 0.002) DIA.
D ₁	1.0 (0.039) DIA. MIN.
D ₂	20.2 (0.795) DIA. MIN.
E	1.75 ± 0.1 (0.069)
F	5.50 (0.127 ± 0.002)
K ₀	3.05 ± 0.1 (0.120) TYP.
N	50.0 (1.970) MIN.
P	4.0 (0.157) TYP.
P ₀	4.0 (0.157) TYP.
P ₂	2.0 (0.079 ± 0.002) TYP.
t	0.3 (0.012) TYP.
T	18.4 (0.72) MAX.
W	12.0 ± 0.3 (0.472 ± 0.012)

THICKNESS OF TOP COVER TAPE 0.10 (0.004) MAX.



hp HEWLETT PACKARD

OPERATOR _____
 HP PART NUMBER _____
 DATE CODE _____
 TAPING DATE _____
 ELEC. VALUE _____
 TOLERANCE _____
 QUANTITY _____
 CUSTOMER PART NUMBER _____



HSDL-44XX Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Ref.
Peak Forward Current (Duty Factor = 20%, Pulse Width = 100 μ s)	I_{Fpk}		500	mA	Fig. 7, 8
DC Forward Current	I_{FDC}		100	mA	Fig. 6
Power Dissipation	P_{DISS}		180	mW	
Reverse Voltage ($I_R = 100 \mu$ A)	V_R	5		V	
Transient Forward Current (10 μ s Pulse)	I_{FTR}		1.0	A	[1]
Operating Temperature	T_O	-40	85	$^{\circ}$ C	
Storage Temperature	T_S	-55	100	$^{\circ}$ C	
Junction Temperature	T_J		110	$^{\circ}$ C	
Lead Solder Temperature [1.6 mm (0.063 in.) from body]			260/5 s	$^{\circ}$ C	
Reflow Soldering Temperatures					
Convection IR			235/90 s	$^{\circ}$ C	
Vapor Phase			215/180 s	$^{\circ}$ C	

Notes:

1. The transient peak current in the maximum nonrecurring peak current the device can withstand without damaging the LED die and the wire bonds.

HSDL-44XX Electrical Characteristics at $T_A = 25^{\circ}$ C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Ref.
Forward Voltage	V_F	1.30 1.40	1.50 1.67 2.15	1.70 1.85	V	$I_{FDC} = 50$ mA $I_{FDC} = 100$ mA $I_{Fpk} = 250$ mA	Fig. 2
Forward Voltage Temperature Coefficient	$\Delta V_F/\Delta T$		-2.1 -2.1		mV/ $^{\circ}$ C	$I_{FDC} = 50$ mA $I_{FDC} = 100$ mA	Fig. 3
Series Resistance	R_S		2.8		Ω	$I_{FDC} = 100$ mA	
Diode Capacitance	C_O		40		pF	0 V, 1 MHz	
Reverse Voltage	V_R	5	20		V	$I_R = 100 \mu$ A	
Thermal Resistance, Junction to Pin	$R\theta_{jp}$		170		$^{\circ}$ C/W		

HSDL-44XX Optical Characteristics at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Ref.
Radiant Optical Power							
HSDL-4400	P_O		16 30		mW	$I_{FDC} = 50\text{ mA}$ $I_{FDC} = 100\text{ mA}$	
HSDL-4420	P_O		16 30		mW	$I_{FDC} = 50\text{ mA}$ $I_{FDC} = 100\text{ mA}$	
Radiant On-Axis Intensity							
HSDL-4400	I_E	1	3 6 15	8	mW/sr	$I_{FDC} = 50\text{ mA}$ $I_{FDC} = 100\text{ mA}$ $I_{FPK} = 250\text{ mA}$	Fig. 4, 5
HSDL-4420	I_E	9	17 32 85	30	mW/sr	$I_{FDC} = 50\text{ mA}$ $I_{FDC} = 100\text{ mA}$ $I_{FPK} = 250\text{ mA}$	Fig. 4, 5
Radiant On-Axis Intensity Temperature Coefficient	$\Delta I_E/\Delta T$		-0.35 -0.35		%/ $^\circ\text{C}$	$I_{FDC} = 50\text{ mA}$ $I_{FDC} = 100\text{ mA}$	
Viewing Angle							
HSDL-4400	$2\theta_{1/2}$		110		deg	$I_{FDC} = 50\text{ mA}$	Fig. 9
HSDL-4420	$2\theta_{1/2}$		24		deg	$I_{FDC} = 50\text{ mA}$	Fig. 10
Peak Wavelength	λ_{PK}	860	875	895	nm	$I_{FDC} = 50\text{ mA}$	Fig. 1
Peak Wavelength Temperature Coefficient	$\Delta\lambda/\Delta T$		0.25		nm/ $^\circ\text{C}$	$I_{FDC} = 50\text{ mA}$	
Spectral Width at FWHM	$\Delta\lambda$		37		nm	$I_{FDC} = 50\text{ mA}$	Fig. 1
Optical Rise and Fall Times, 10%-90%	t_r/t_f		40		ns	$I_{FPK} = 50\text{ mA}$	
Bandwidth	f_c		9		MHz	$I_{FDC} = 50\text{ mA}$ $\pm 10\text{ mA}$	Fig. 11

HSDL-54XX Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit
Power Dissipation	P_{DISS}		150	mW
Reverse Voltage ($I_R = 100 \mu A$)	V_R		40	V
Operating Temperature	T_O	-40	85	°C
Storage Temperature	T_S	-55	100	°C
Junction Temperature	T_J		110	°C
Lead Solder Temperature [1.6 mm (0.063 in.) from body]			260/5 s	°C
Reflow Soldering Temperatures				
Convection IR			235/90 s	°C
Vapor Phase			215/180 s	°C

HSDL-54XX Electrical Characteristics at $T_A = 25^\circ C$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Ref.
Forward Voltage	V_F		1.80		V	$I_{FDC} = 50 \text{ mA}$	
Breakdown Voltage	V_{BR}	40			V	$I_R = 100 \mu A$, $E_e = 0 \text{ mW/cm}^2$	
Reverse Dark Current	I_D		1	5	nA	$V_R = 5 \text{ V}$, $E_e = 0 \text{ mW/cm}^2$	Fig. 12
Series Resistance	R_S		2000		Ω	$V_R = 5 \text{ V}$, $E_e = 0 \text{ mW/cm}^2$	
Diode Capacitance	C_O		5		pF	$V_R = 0 \text{ V}$, $E_e = 0 \text{ mW/cm}^2$ $f = 1 \text{ MHz}$	Fig. 16
Open Circuit Voltage	V_{OC}		375		mV	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$	
Temperature Coefficient of V_{OC}	$\Delta V_{OC}/\Delta T$		-2.2		mV/K	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$	
Short Circuit Current	I_{SC}					$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$	
HSDL-5400			1.6		μA		
HSDL-5420			4.3		μA		
Temperature Coefficient of I_{SC}	$\Delta I_{SC}/\Delta T$		0.16		%/K	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$	
Thermal Resistance, Junction to Pin	$R\theta_{jp}$		170		°C/W		

HSDL-54XX Optical Characteristics at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Ref.
Photocurrent	I_{PH}	0.8	1.6		μA	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$ $V_R = 5 \text{ V}$	Fig. 14, 15
HSDL-5400							
HSDL-5420							
Temperature Coefficient of I_{PH}	$\Delta I_{PH}/\Delta T$		0.1		%/K	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$ $V_R = 5 \text{ V}$	Fig. 13
Radiant Sensitive Area	A		0.15		mm^2		
Absolute Spectral Sensitivity	S		0.5		A/W	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$ $V_R = 5 \text{ V}$	
Viewing Angle	$2\theta_{1/2}$		110		deg		Fig. 18
HSDL-5400							
HSDL-5420							
Wavelength of Peak Sensitivity	λ_{PK}		875		nm	$E_e = 1 \text{ mW/cm}^2$ $V_R = 5 \text{ V}$	Fig. 17
Spectral Bandwidth	$\Delta\lambda$		770-1000		nm	$E_e = 1 \text{ mW/cm}^2$ $V_R = 5 \text{ V}$	Fig. 17
Quantum Efficiency	η		70		%	$E_e = 1 \text{ mW/cm}^2$ $\lambda_{PK} = 875 \text{ nm}$ $V_R = 5 \text{ V}$	
Noise Equivalent Power	NEP		6.2×10^{-15}		$\text{W/Hz}^{1/2}$	$V_R = 5 \text{ V}$ $\lambda_{PK} = 875 \text{ nm}$	
Detectivity	D		6.3×10^{12}		$\text{cm}^* \text{ Hz}^{1/2}/\text{W}$	$V_R = 5 \text{ V}$ $\lambda_{PK} = 875 \text{ nm}$	
Optical Rise and Fall Times, 10%-90%	t_r/t_f		7.5		ns	$V_R = 5 \text{ V}$ $R_L = 1 \text{ k}\Omega$ $\lambda_{PK} = 875 \text{ nm}$	
Bandwidth	f_c		50		MHz	$V_R = 5 \text{ V}$ $R_L = 1 \text{ k}\Omega$ $\lambda_{PK} = 875 \text{ nm}$	

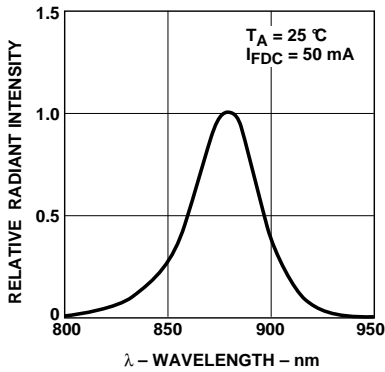


Figure 1. Relative Radiant Intensity vs. Wavelength.

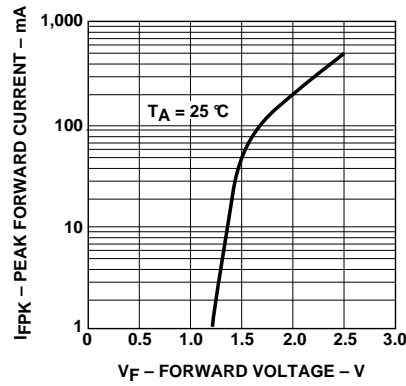


Figure 2. Peak Forward Current vs. Forward Voltage.

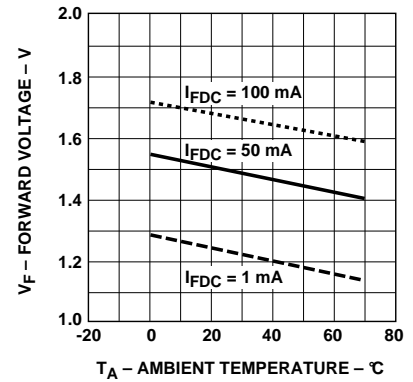


Figure 3. Forward Voltage vs Ambient Temperature.

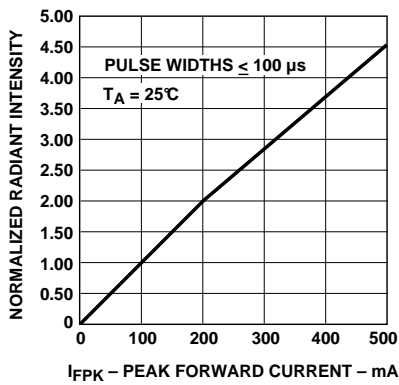


Figure 4. Normalized Radiant Intensity vs. Peak Forward Current.

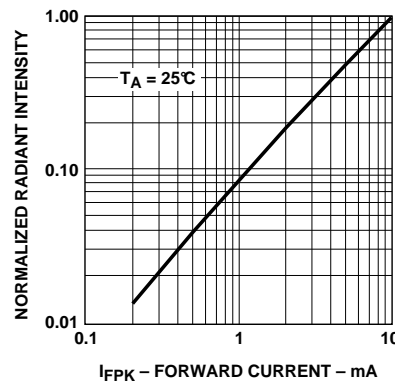


Figure 5. Normalized Radiant Intensity vs. Peak Forward Current (0 to 10 mA).

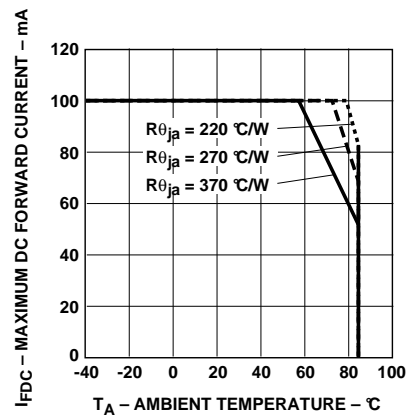


Figure 6. Maximum DC Forward Current vs. Ambient Temperature. Derated Based on $T_{JMAX} = 110^{\circ}C$.

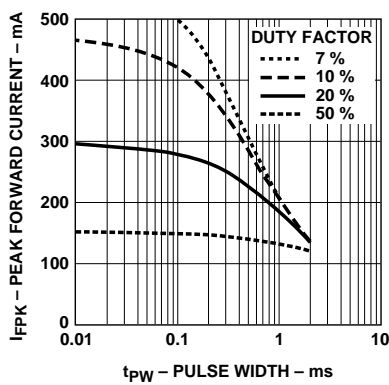


Figure 7. Maximum Peak Forward Current vs. Duty Factor.

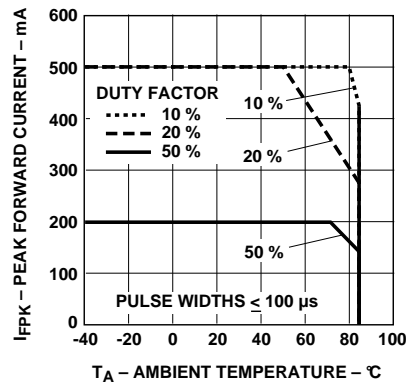


Figure 8. Maximum Peak Forward Current vs. Ambient Temperature. Derated Based on $T_{JMAX} = 110^{\circ}C$.

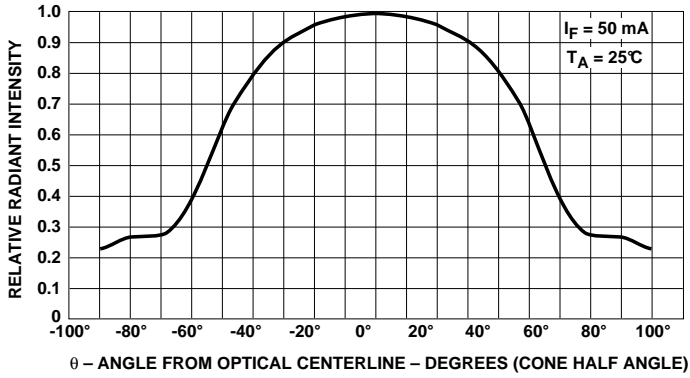


Figure 9. Relative Radiant Intensity vs. Angular Displacement HSDL-4400.

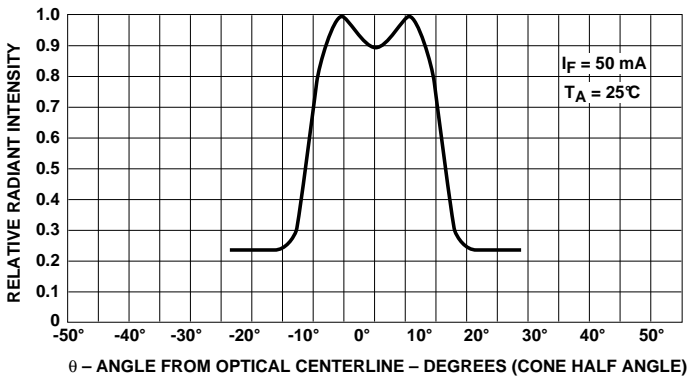


Figure 10. Relative Radiant Intensity vs. Angular Displacement HSDL-4420.

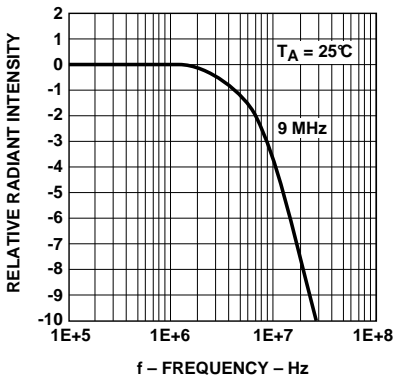


Figure 11. Relative Radiant Intensity vs. Frequency.

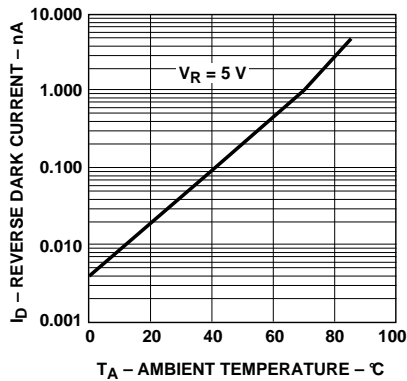


Figure 12. Reverse Dark Current vs. Ambient Temperature.

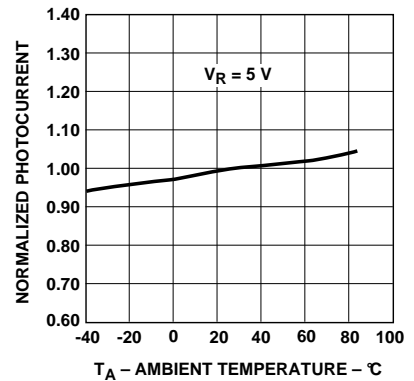


Figure 13. Relative Reverse Light Current vs. Ambient Temperature.

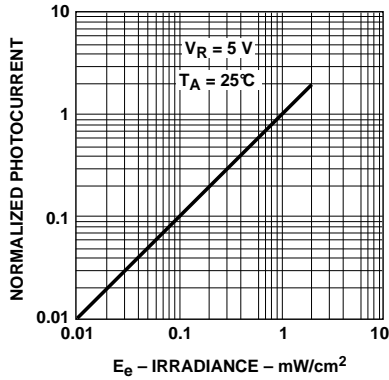


Figure 14. Reverse Light Current vs. Irradiance

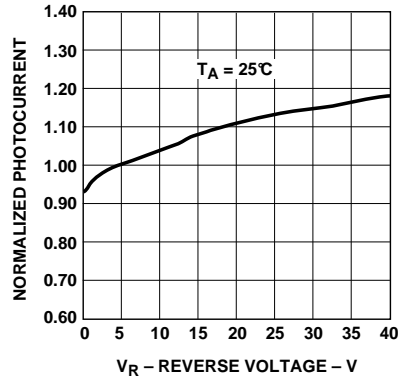


Figure 15. Reverse Light Current vs. Reverse Voltage.

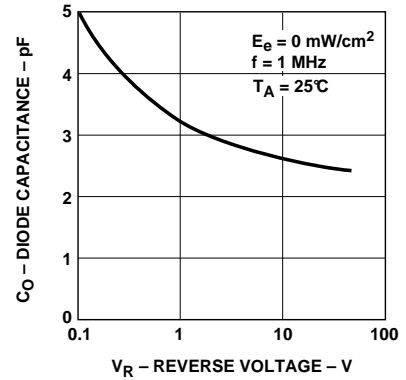


Figure 16. Diode Capacitance vs. Reverse Voltage.

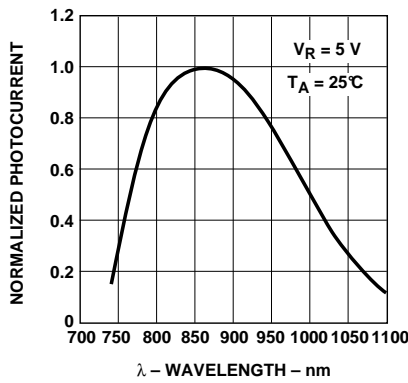


Figure 17. Relative Spectral Sensitivity vs. Wavelength.

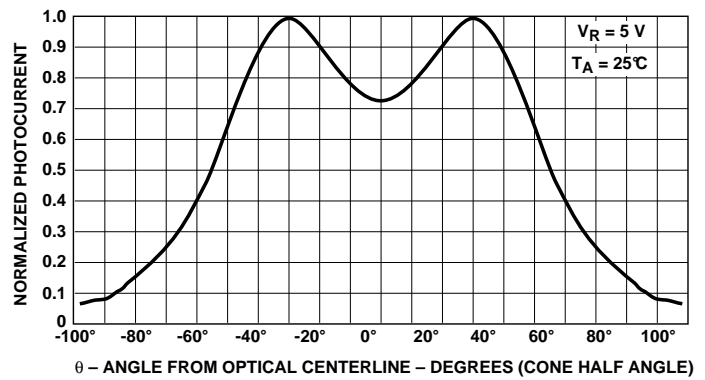


Figure 18. Relative Radiant Intensity vs. Angular Displacement. HSDL-5400.

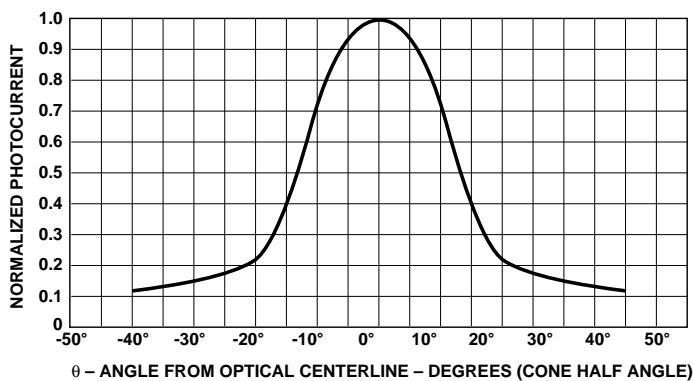


Figure 19. Relative Radiant Intensity vs. Angular Displacement. HSDL-5420.

Note: At the time of this publication, Light Emitting Diodes (LEDs) that are contained in this product are regulated for eye safety in Europe by the Commission for European Electrotechnical Standardization (CENELEC) EN60825-1. Please refer to Application Briefs I-008, I-009, I-015 for more information.